MBRS7XX SERIES SCHOTTKY BARRIER RECTIFIER

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MBRS735 THRU MBRS760

SCHOTTKY BARRIER RECTIFIER



REVERSE VOLTAGE: 35 to 60 VOLTS FORWARD CURRENT: 7.5 AMPERE

FEATURES

- · For surface mounted application
- · Metal silicon junction, majority carrier conduction
- · Guard ring for overvoltage protection
- · Low power loss, high efficiency
- · For use in low voltage, high frequency inverters, free whelling, and polarity protection applications
- \cdot High temperature soldering guaranteed: $250^{\circ}\text{C}/10$ seconds, 0.25" (6.35mm) from case

MECHANICAL DATA

Case: Molded plastic, D²PAK

Epoxy: UL 94V-O rate flame retardant

Terminals: Leads solderable per MIL-STD-202

method 208 guaranteed
Polarity: As marked
Mounting position: Any
Weight: 0.06ounce, 1.70gram

.185 (4.70) .175 (4.44) .055 (1.40) .045 (1.14) .055 (1.40) .045 (1.14) .055 (1.40) .045 (1.14) .045 (1.14) .045 (1.14) .045 (1.14) .045 (1.14) .045 (1.14) .045 (1.14) .045 (1.14) .045 (1.14) .045 (1.14)

D²PAK

PIN 1 O PIN 2 O H CASE

Case Positive

PIN 2 O H CASE

Case Negative

Suffix "R"

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	MBRS735	MBRS745	MBRS750	MBRS760	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	35	45	50	60	Volts
Maximum RMS Voltage	V _{RMS}	24	31	35	42	Volts
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	Volts
Maximum Average Forward Rectified Current See Fig. 1	I _(AV)	7.5				Amp
Peak repetitive forward current (sq. wave, 20 KHz) at $T_{\rm C}$ = 105°C	I_{FRM}	15				Amp
Peak Forward Surge Current, 8.3ms single half-sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	150				Amp
Peak repetitive reverse current at tp = 2.0µs, 1KHz	I _{RRM}	1.0		0.5		Amp
$\begin{array}{c} \text{ at } I_F = 7.5 \text{A}, T_C = 25^{\circ} \text{C} \\ \text{Maximum Forward} & \text{at } I_F = 7.5 \text{A}, T_C = 125^{\circ} \text{C} \\ \text{Voltage (Note 1)} & \text{at } I_F = 15 \text{A}, T_C = 25^{\circ} \text{C} \\ \text{at } I_F = 15 \text{A}, T_C = 125^{\circ} \text{C} \end{array}$	V _F	- 0.57 0.84 0.72		0.75 0.65 - -		Volts
Maximum Reverse Current at T_C =25°C at Rated DC Blocking Voltage T_C =125°C	I_R	0	.1		0.5 50	mAmp
Voltage rate of change (rated V _R)	dv/dt	10,000			V/µs	
Typical Thermal Resistance	$R_{ heta JC}$	3.0			°C/W	
Operating Temperature Range	T_{J}	-55 to +150			ဗ	
Storage Temperature Range	Tstg	-55 to +175				င

NOTES:

1- Pulse test: 300µs pulse width, 1% duty cycle



RATINGS AND CHARACTERISTIC CURVES

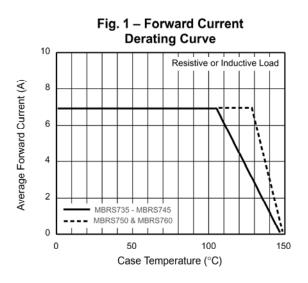


Fig. 2 - Maximum Non-Repetitive **Peak Forward Surge Current** 175 $T_J = T_J \text{ max.}$ 8.3ms Single Half Sine-Wave Peak Forward Surge Current (A) 150 (JEDEC Method) 125 100 75 50 25 10 100 Number of Cycles at 60 Hz

